## 2SC4643

## Silicon NPN Epitaxial

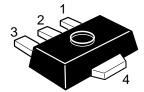
# **HITACHI**

### Application

UHF / VHF wide band amplifier

#### Outline

**UPAK** 



- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector (Flange)

#### 2SC4643

### **Absolute Maximum Ratings** (Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	15	V
Collector to emitter voltage	$V_{\text{CEO}}$	9	V
Emitter to base voltage	$V_{EBO}$	1.5	V
Collector current	I <sub>c</sub>	50	mA
Collector power dissipation	P <sub>c</sub>	400	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

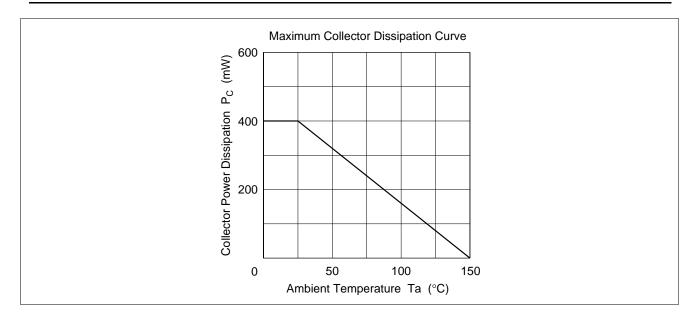
#### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	15	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	1	μΑ	V <sub>CB</sub> = 12 V, I <sub>E</sub> = 0
	I <sub>CEO</sub>	_	_	1	mA	$V_{CE} = 9 \text{ V}, \text{ R}_{BE} = \infty$
Emitter cutoff current	$I_{EBO}$	_	_	10	μΑ	$V_{EB} = 1.5 \text{ V}, I_{C} = 0$
DC current transfer ratio	$h_{FE}$	40	120	250	_	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}$
Collector output capacitance	Cob	_	1.0	1.7	pF	$V_{CB} = 5 \text{ V}, I_{E} = 0,$ f = 1MHz
Gain bandwidth product	f⊤	5.5	8.0	_	GHz	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}$
Power gain	PG	7.5	10.5	_	dB	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA},$ f = 900 MHz
Noise figure	NF	_	1.2	2.5	dB	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA},$ f = 900 MHz

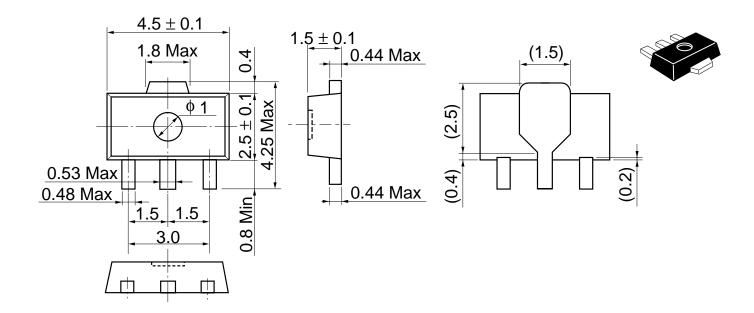
Note: Marking is "DR".

See characteristic curve of 2SC4592

2SC4643



Unit: mm



Hitachi Code	UPAK
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.050 g

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